- Inputs Are TTL-Voltage Compatible
- Contains Four Flip-Flops with Double-Rail Outputs
- Clock Enable Latched to Avoid False Clocking
- Applications Include: Buffer/Storage Registers, Shift Registers, Pattern Generators
- Flow-Through Architecture to Optimize PCB Layout
- Center-Pin V<sub>CC</sub> and GND Configurations to Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-µm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small Outline Packages, and Standard Plastic 300-mil DIPs

#### (TOP VIEW) 1Q 20 1Q 2Q 🛛 2 19 CLKEN 2Q [ 3 18 🛮 1D GND [ 4 17 2D GND [] 5 16 V<sub>CC</sub> GND **1** 6 15 V<sub>CC</sub> GND 7 14 1 3D 3Q [] 8 13 **1** 4D 3Q [] 9 12 CLK 11 🛮 4 🗖 4Q [] 10

DW OR N PACKAGE

#### description

These circuits are positive-edge-triggered D-type flip-flops with a clock-enable input.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse if CLKEN is low. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output. The circuits are designed to prevent false clocking by transitions at the CLKEN input.

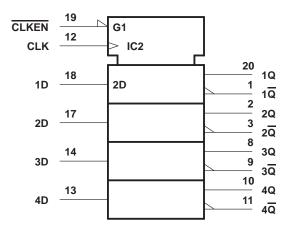
The 74ACT11379 is characterized for operation from – 40°C to 85°C.

## FUNCTION TABLE (each flip-flop)

	•						
INPUTS			OUTPUTS				
CLKEN	CLK	D	Q	Q			
Н	Х	Х	Q <sub>0</sub>	$\overline{Q}_0$			
L	$\uparrow$	Н	Н	L			
L	$\uparrow$	L	L	Н			
Х	L	Χ	$Q_0$	$\overline{Q}_0$			

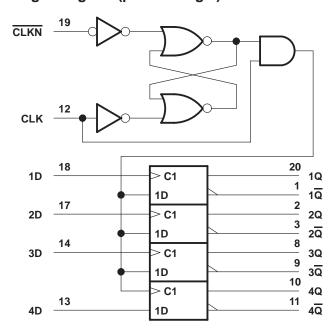
EPIC is a trademark of Texas Instruments Incorporated.

### logic symbol†



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub>	$\dots \dots -0.5 V$ to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	± 20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	$\dots \dots \pm 50 \text{ mA}$
Continuous output current, I <sub>O</sub> (V <sub>O</sub> = 0 to V <sub>CC</sub> )	$\dots \dots \pm 50 \text{ mA}$
Continuous current through V <sub>CC</sub> or GND	$\dots \dots \pm 200 \text{ mA}$
Storage temperature range	– 65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions

		MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
$V_{IL}$	Low-level input voltage		0.8	V
VI	Input voltage	0	VCC	V
VO	Output voltage	0	VCC	V
ІОН	High-level output current		-24	mA
loL	Low-level output current		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
TA	Operating free-air temperature	- 40	85	°C



NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	IVIIIN	WAX	UNII
	I <sub>OH</sub> = - 50 μA	4.5 V	4.4			4.4		V
Voн		5.5 V	5.4			5.4		
	I <sub>OH</sub> = - 24 mA	4.5 V	3.94			3.8		
	10H = - 24 IIIA	5.5 V	4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V				3.85		
	ΙΟL = 50 μΑ	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
V <sub>OL</sub>	I <sub>OL</sub> = 24 mA	4.5 V			0.36		0.44	V
		5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V					1.65	
I <sub>I</sub>	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		± 1	μА
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			8		80	μΑ
Δl <sub>CC</sub> ‡	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V			0.9		1	mA
C <sub>i</sub>	$V_I = V_{CC}$ or GND	5 V		4				pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

		T <sub>A</sub> :		T <sub>A</sub> = 25°C		MAX	UNIT	
			MIN	MAX	MIN	WAX	UNII	
fclock	Clock frequency		0	100	0	100	MHz	
	Pulse duration	CLK high	5		5			
t <sub>W</sub>	ruise duration	CLK low	5		5		ns	
		Data	5		5			
t <sub>su</sub>	Setup time, before CLK↑	CLKEN high	3.5		3.5		ns	
		CLKEN low	3.5		3.5			
t <sub>h</sub>	Hold time, after CLK ↑	CLKEN inactive or active, data	0		0		ns	

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	DADAMETED	FROM	ТО	T	A = 25°C		MIN MAX	MINI	MAY III	MAV	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	WAA		UNIT			
f <sub>max</sub>			100	125		100		MHz			
t <sub>PLH</sub>	CLK	A Q \overline{\text{Q}}	2.2	5	6.6	2.2	7.4	20			
<sup>t</sup> PHL		Any Q or Q	3.1	7.2	9.8	3.1	11.2	ns			

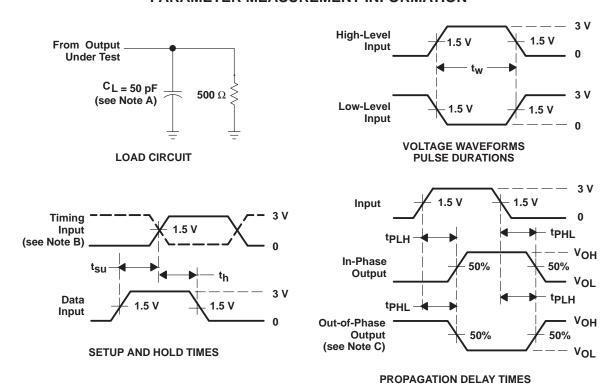
## operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	38	pF



<sup>‡</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \ \Omega$ ,  $t_f = 3 \ ns$ ,  $t_f = 3 \ ns$ .
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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